

140 COMMERCE DRIVE MONTGOMERYVILLE, PA 18936-1013

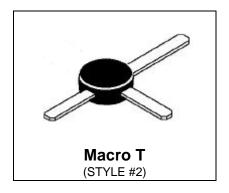
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BFR90

RF & MICROWAVE DISCRETE LOW POWER TRANSISTORS

Features

- High Current-Gain Bandwidth Product, fT = 5.0 GHz (typ) @ IC = 14 mA
- Low Noise Figure NF = 2.4 dB (typ) @ f = 0.5 GHz
- High Power Gain Gmax = 18dB (typ) @ f = 0.5 GHz



DESCRIPTION: Designed primarily for use in high-gain, low noise, small-signal amplifiers. Also used in applications requiring fast switching times.

ABSOLUTE MAXIMUM RATINGS (Tcase = 25°C)

Symbol	Parameter	Value	Unit
V _{CEO}	Collector-Emitter Voltage	15	Vdc
V _{CBO}	Collector-Base Voltage	20	Vdc
V_{EBO}	Emitter-Base Voltage	3.0	Vdc
Ic	Collector Current	30	mA

Thermal Data

mermar bata		
P Total Device Dissipation @ TA = 60°C Derate above 60°C	180 2.0	mWatts mW/ ° C



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ELECTRICAL SPECIFICATIONS (Tcase = 25°C)

STATIC

(off)

Symbol	Test Conditions				
		Min.	Тур.	Max.	Unit
BVCEO	Collector-Emitter Breakdown Voltage (IC = 1.0 mAdc, IB = 0)	15	-	-	Vdc
BVCB0	Collector-Base Breakdown Voltage (IC = 0.1 mAdc, IE = 0)	20	-	-	Vdc
BVEBO	Emitter-Base Breakdown Voltage (IE = 0.1 mAdc, IC = 0)	3.0	-	-	Vdc
ICBO	Collector Cutoff Current (VCB = 10 Vdc, VBE = 0 Vdc)	-	-	50	nA
on)		•	•		
HFE	DC Current Gain (IC = 14 mAdc, VCE = 10 Vdc)	25	-	250	-

DYNAMIC

Symbol	Test Conditions				
		Min.	Тур.	Max.	Unit
Ftau	Current-Gain – Bandwidth Product (IC = 14 mA, VCE = 10 Vdc, f = 0.5 GHz)	-	5.0	-	GHz
ССВ	Output Capacitance (VCB = 10 Vdc, IE = 0, f = 1.0 MHz)	-	0.5	1.0	pF



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FUNCTIONAL

Symbol	Test Conditions		Value					
		Min.	Тур.	Max.	Unit			
	Noise Figure							
NF	(IC = 2.0 mAdc, VCE = 10 Vdc, f = 0.5 GHz)	-	2.4	-	dB			
	(IC = 2.0 mAdc, VCE = 10 Vdc, f = 1.0 GHz)	-	3.0	-				
	Power Gain at Optimum Noise Figure							
GNF	(IC = 2.0 mAdc, VCE = 10 Vdc, f = 0.5 GHz)	-	15	-	dB			
	(IC = 2.0 mAdc, VCE = 10 Vdc, f = 1.0 GHz)	-	10	-				
S ₂₁ ²	Insertion Gain							
10211	(IC = 14 mAdc, VCE = 10 Vdc, f = 0.5 GHz)	15	16	-	dB			
	(IC = 14 mAdc, VCE = 10 Vdc, f = 1.0 GHz)		11					
MSG	Maximum Stable Gain							
	(IC = 14 mAdc, VCE = 10 Vdc, f = 0.5 GHz)	-	20	-	dB			
	(IC = 14 mAdc, VCE = 10 Vdc, f = 1.0 GHz)		15					
G U max	Maximum Unilateral Gain (1)							
U max	(IC = 14 mAdc, VCE = 10 Vdc, f = 0.5 GHz)	-	18	-	dB			
	(IC = 14 mAdc, VCE = 10 Vdc, f = 1.0 GHz)		12.5					

Table 1. Common Emitter S-Parameters, @ VCE = 10 V, IC = 14 mA

f	S	11	S21		s	12	9	S22
(MHz)	S11	∠ ф	S21	∠ ф	S12	∠ ф	S22	∠ ф
100	0.382	-41	21.21	141	0.016	79	0.718	-9
200	0.282	-77	14.85	116	0.028	74	0.662	-18
300	0.217	-101	10.71	104	0.039	74	0.599	-20
500	0.162	-131	6.78	91	0.061	76	0.558	-24
700	0.140	-151	4.98	83	0.082	76	0.55	-28
800	0.135	-159	4.42	80	0.093	76	0.552	-29
1000	0.124	-176	3.59	74	0.117	75	0.553	-33





RF Low Power PA, LNA, and General Purpose Discrete Selector Guide

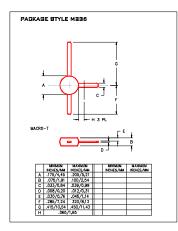
Packade	Device	Туре	GPE Freq (MHz)	Pout (watts)	GPE (dB)	Efficiency (%)	GPE VCC	BVCEO	IC max (mA)
SO-8	MRF4427, R2	NPN	175	0.15	18	60	12	20	400
TO-39	2N4427	NPN	175	1	10	50	12	20	400
POWER MACRO	MRF553	NPN	175	1.5	11.5	60	12.5	16	500
POWER MACRO	MRF553T	NPN	175	1.5	11.5	50	12.5	16	500
TO-39	MRF607	NPN	175	1.75	11.5	50	12.5	16	330
TO-39	2N6255	NPN	175	3	7.8	50	12.5	18	1000
TO-72	2N5179	NPN	200		20		6	12	50
MACRO X	MRF559	NPN	512	0.5	10	65	7.5	16	150
MACRO X	MRF559	NPN	512	0.5	13	60	12.5	16	150
TO-39	2N3866A	NPN	400	1	10	45	28	30	400
SO-8	MRF3866, R1, R2	NPN	400	1	10	45	28	30	400
POW ER MACRO	MRF555	NPN	470	1.5	11	50	12.5	16	400
POW ER MACRO	MRF555T	NPN	470	1.5	11	50	12.5	16	400
MACRO X	MRF559	NPN	870	0.5	6.5	70	7.5	16	150
MACRO X	MRF559	NPN	870	0.5	9.5	65	12.5	16	150
SO-8	MRF8372,R1,R2	NPN	870	0.75	8	55	12.5	16	200
POW ER MACRO	MRF557	NPN	870	1.5	8	55	12.5	16	400
POW ER MACRO	MRF557T	NPN	870	1.5	8	55	12.5	16	400

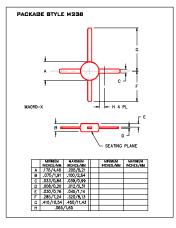
Package	Device	Type	Freq (MHz)	NF (dB)	NF IC (mA)	NF VCE	GN (dB)	Gu Max (dB)	Ftau (MHz)	Ccb(pF)	BVCEO	IC max (mA)
TO-39	2N5109	NPN	200	3	10	15		12	1200	3.5	20	400
TO-39	MRF5943C	NPN	200	3.4	30	15		11.4	1000		30	400
S O - 8	MRF5943, R1, R2	NPN	200	3.4	30	15		15	1300		30	400
TO-72	2N5179	NPN	200	4.5	1.5	6		17	900	1	12	50
TO-72	2N2857	NPN	300	5.5	50	6		13	1600	1	15	40
TO-39	MRF517	NPN	300	7.5	50	15		5.5	4600	3	25	150
TO-72	MRF904	NPN	450	1.5	5	6		11	4000	1	15	30
TO-72	2N6304	NPN	450	5	2	5		14	1400	1	15	50
MACRO T	BFR91	NPN	500	1.9	2	5	11	16.5	5000	1	12	35
MACRO T	BFR96	NPN	500	2	10	10		14.5	500	2.6	15	100
S O - 8	MRF5812, R1, R2	NPN	500	2	50	10	15.5	17.8	5000		15	200
MACRO X	MRF581A	NPN	500	2	50	10	14	15	5000		15	200
Macro	BFR90	NPN	500	2.4	2	10	15	18	5000	1	15	30
TO-72	BFY90	NPN	500	2.5	2	5		20	1300		15	50
TO-72	MRF914	NPN	500	2.5	5	10		15	4500		12	40
MACRO X	MRF581	NPN	500	2.5	50	10	15	17.8	5000		16	200
TO-39	MRF586	NPN	500	3	90	15	11	14.5	4500	2.2	17	200
MACRO X	MRF951	NPN	1000	1.3	5	6	14	17	8000	0.45	10	100
MACRO X	MRF571	NPN	1000	1.5	10	6	10		8000	1	10	70
MACRO T	BFR91	NPN	1000	2.5	2	5	8	11	5000	1	12	35
MACRO T	BFR90	NPN	1000	3	2	10	10	12.5	5000	1	15	30
TO-39	MRF545	PNP						14	1400	2	70	400
TO-39	MRF544	NPN						13.5	1500		70	400

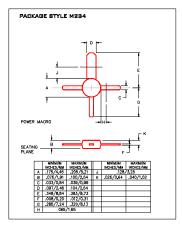
RF (Low Power PA / General Purpose) Selection Guide

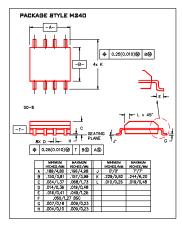
RF (LNA / General Purpose) Selection Guide

Low Cost RF Plastic Package Options









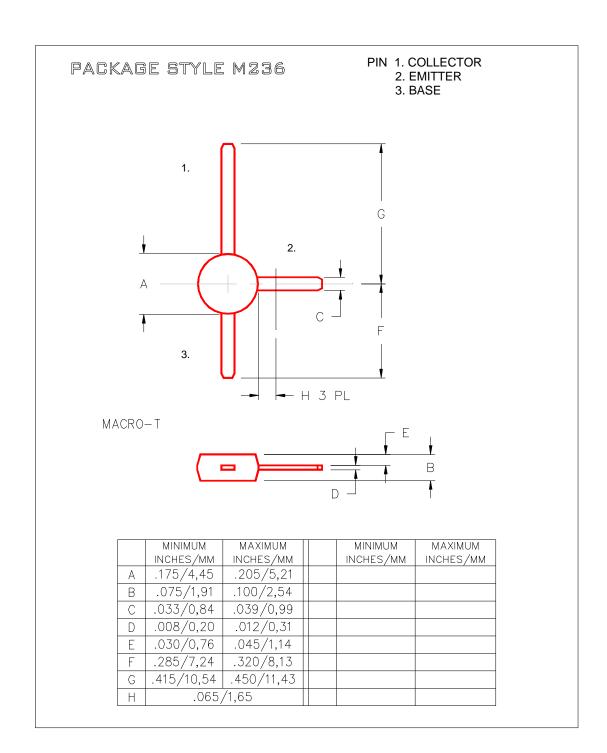
Macro T Macro X

Power Macro

SO-8







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